

Green Products

SK510B SCHOTTKY RECTIFIER

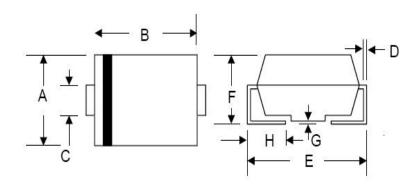
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Disk drives
- · Battery charging

Features:

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Green products in compliance the ROHS directive
- This is a Pb Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm

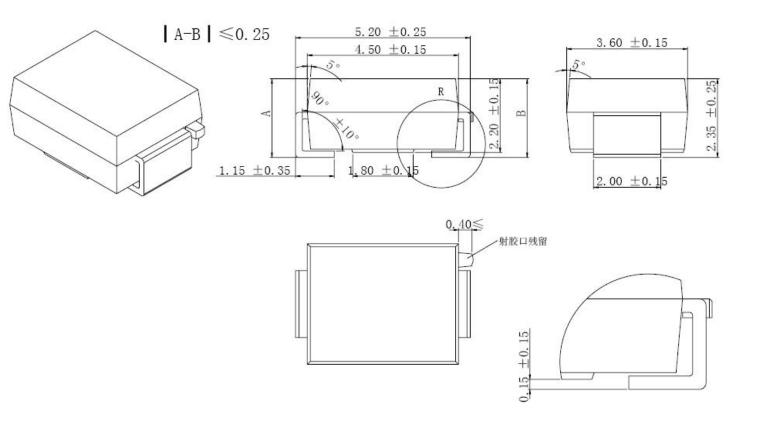


SMB/DO-214AA					
Dim	Min	Max	Min	Max	
Α	3.30	3.94	0.130	0.155	
В	4.06	4.70	0.160	0.185	
С	1.91	2.11	0.075	0.083	
D	0.152	0.305	0.006	0.012	
Е	5.08	5.59	0.2	0.220	
F	2.13	2.44	0.084	0.096	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.27	0.029	0.05	
	in mm		In inch		

OPTION 1



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OPTION 2(JK)

SMB



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Marking Diagram:



Where XXXXX is YYWWL

SK = Device Type

5 = Forward Current (5A) 10 = Reverse Voltage (100V)

B = Package type

YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SK510B	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	100	V
Average Rectified Forward	I _{F(AV)}	50% duty cycle @T _L =115°C,	5	Α
Current		rectangular wave form	5	
Peak one Cycle Non- repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	120	А



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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.85	V
(per leg) *	V _{F2}	@ 5 A, Pulse, T _J = 125 °C	0.70	V
Reverse Current (per leg) *	I _{R1}	@V _R = rated VR	0.1	mA
		T _J = 25 °C		
	I _{R2}	@V _R = rated VR	2.0	mA
		T _J = 100 °C		
Junction Capacitance	Ст	@V _R = 4V, T _C = 25 °C	200	pF
(per leg)		f _{SIG} = 1MHz		
Voltage Rate of Change	dv/dt	-	10,000	V/us

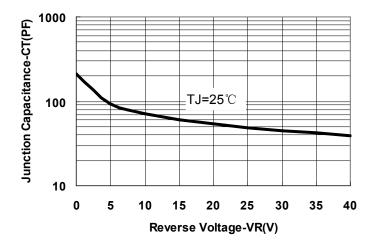
^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Lead	$R_{ heta JL}$	-	17	°C/W
Typical Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	-	75	°C/W
Approximate Weight	wt	-	0.68	g
Case Style		SMB		



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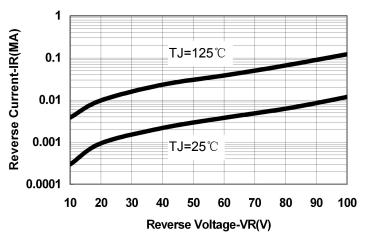


Fig.1-Typical Junction Capacitance Vs. Reverse Voltage

Fig.2-Typical Values Of Reverse Current Vs. Reverse Voltage

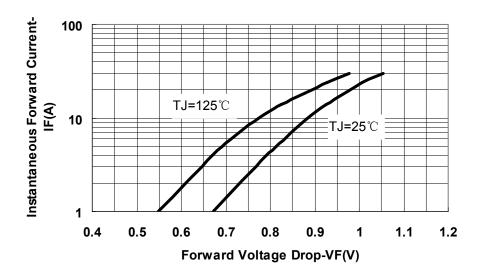


Fig.3-Typical Forward Voltage Drop Characteristics





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